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IN THE CONTED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Douglas Brisbin et al.

Application No.: 10/616,381

Filed: July 9, 2003

For: LDMOS TRANSISTOR STRUCTURE

FOR IMPROVING HOT CARRIER

RELIABILITY

Group Art Unit: 2811

Examiner: Unknown

INFORMATION DISCLOSURE STATEMENT

121 Spear Street, Suite 290 San Francisco, CA 94105 (415) 512-1312

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope, addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on October 23, 2003.

STALLMAN & POLLOCK LLP

Dated: 10/23/2003

Georgia Kastith

Sir:

Applicant(s) submit(s) herewith patents, publications or other information [attached hereto and listed on the attached Form PTO-1449 (modified)] of which they are aware, which they believe(s) may be material to the examination of this application and in respect of which there may be a duty to disclose in accordance with 37 CFR § 1.56.

This Information Disclosure Statement:

- (a) accompanies the new patent application submitted herewith. 37 CFR § 1.97(a).
- (b) is filed within three months after the filing date of the application or within three months after the date of entry of the national stage of a PCT application as set forth in 37 CFR § 1.491.
- (c) as far as is known to the undersigned, is filed before the mailing date of a first Office Action on the merits, or before a first office action after filing a Request for Continued Examination under §1.114.
- (d) is filed after the first office action and more than three months after the application's filing date or PCT national stage date of entry filing but, as far as is

Atty Docket No.: NSC1-M2900 [P05632]

10/616,381 <u>PATENT</u>

known to the undersigned, prior to the mailing date of either a final rejection or a notice of allowance, whichever occurs first, and is accompanied by either the fee (\$180) set forth in 37 CFR § 1.17(p) or a certification as specified in 37 CFR § 1.97(e), as checked below. (e) is filed after the mailing date of either a final rejection or a notice of allowance, whichever occurred first, and the Issue Fee has not been paid, and is accompanied by the fee (\$130) set forth in 37 CFR § 1.17(i)(1) and a certification as specified in 37 CFR § 1.97(e), as checked below. This document is to be considered as a petition requesting consideration of the information disclosure statement. [If either of boxes (d) or (e) is checked above, the following "certification" under 37 CFR § 1.97(e) may need to be completed.] The undersigned certifies that: (f) Each item of information contained in the information disclosure statement was cited in a communication mailed from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this information disclosure statement. (g) No item of information contained in this information disclosure statement was cited in a communication mailed from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned after making reasonable inquiry, was known to any individual designated in 37 CFR § 1.56(c) more than three months prior to the filing of this information disclosure statement. A list of the patent(s) or publication(s) is set forth on the attached Form PTO-1449 (Modified). A copy of the items on PTO-1449 (Modified) is supplied herewith, except as noted below. Those patent(s) or publication(s) which are marked with an asterisk (*) in the attached form PTO-1449 (Modified) are not supplied because they are (a) either U.S. Patents and this an application filed after June 30, 2003, or (b) were previously cited by or submitted to the Office in a prior application no. ______, filed and relied upon in this application for an earlier filing date under 35 U.S.C. § 120. A concise explanation of relevance of the items listed on form PTO-1449 (Modified) is:

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(k) not given

(-)	(1)		given	for	each	listed	item
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- (m) given for only non-English language listed item(s) [Required]
- (n) is in the form of an English language copy of a Search Report from a foreign patent office, issued in a counterpart application, which refers to the relevant portions of the references [copy attached].

The Examiner is reminded that a "concise explanation of the relevance" of the submitted items "may be nothing more than identification of the particular figure or paragraph of the patent or publication which has some relation to the claimed invention," MPEP § 609.

While the information and references disclosed in this Information Disclosure Statement may be "material" pursuant to 37 CFR § 1.56, it is not intended to constitute an admission that any patent, publication or other information referred to therein is "prior art" for this invention unless specifically designated as such.

In accordance with 37 CFR § 1.97(g), the filing of this Information Disclosure Statement shall not be construed to mean that a search has been made or that no other material information as defined in 37 CFR § 1.56(a) exists. It is submitted that the Information Disclosure Statement is in compliance with 37 CFR § 1.98 and MPEP § 609 and the Examiner is respectfully requested to consider the listed references.

The Commissioner is hereby authorized to charge our Deposit Account No. 50-1703, under Order No. NSC1-M2900, for any fees required in connection with the filing of this Information Disclosure Statement. A duplicate copy of this Notice is enclosed for this purpose. In particular, in the event that an Office Action has crossed in the mail with this Information Disclosure Statement, the Commissioner is authorized to charge the above-named deposit account for any fees required pursuant to CFR §§ 1.17(p) or 1.17(i)(1).

Respectfully submitted,

STALLMAN & POLLOCK LLP

Dated: 10 -22 - 93

Brian J. Keating (Reg. No. 39,520)

Attorneys for Applicant(s)

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INFORMATION DISCLOSURE CTATION (Use several sheets if necessary)

Docket Number (Optional) NSC1-M2900 [P05632]	Application Number	
Applicant(s) Douglas Brisbin et al.		
Filing Date	Group Art Unit	

U.S. PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	Name	CLASS	SUBCLASS	FILING DATE
AA	5,517,046	05/14/1996	Hsing et al.	257	336	02/06/1995
AB	6,144,069	11/07/2000	Tung	257	335	08/03/1999
AC	6,177,834	01/23/2001	Blair et al.	327	566	12/02/1998
AD	6,297,533	10/02/2001	Mkhitarian	257	336	04/30/1998
AE	6,548,839	04/15/2003	Strachan et al.	257	204	02/20/2002
AF	6,566,710	05/20/2003	Strachan et al.	257	341	08/29/2001
	AA AB AC AD AE	NUMBER AA 5,517,046 AB 6,144,069 AC 6,177,834 AD 6,297,533 AE 6,548,839	Number AA 5,517,046 05/14/1996 AB 6,144,069 11/07/2000 AC 6,177,834 01/23/2001 AD 6,297,533 10/02/2001 AE 6,548,839 04/15/2003	NUMBER NUMBER AA 5,517,046 05/14/1996 Hsing et al. AB 6,144,069 11/07/2000 Tung AC 6,177,834 01/23/2001 Blair et al. AD 6,297,533 10/02/2001 Mkhitarian AE 6,548,839 04/15/2003 Strachan et al.	NUMBER S,517,046 05/14/1996 Hsing et al. 257 AB 6,144,069 11/07/2000 Tung 257 AC 6,177,834 01/23/2001 Blair et al. 327 AD 6,297,533 10/02/2001 Mkhitarian 257 AE 6,548,839 04/15/2003 Strachan et al. 257	NUMBER Hsing et al. 257 336 AB 6,144,069 11/07/2000 Tung 257 335 AC 6,177,834 01/23/2001 Blair et al. 327 566 AD 6,297,533 10/02/2001 Mkhitarian 257 336 AE 6,548,839 04/15/2003 Strachan et al. 257 204

FOREIGN PATENT DOCUMENTS

	DOCUMENT					TRAN	SLATION
REF	Number	DATE	COUNTRY	CLASS	SUBCLASS	YES	No

OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

 AG	D. Brisbin et al., "Design Optimization of N-LDMOS Transistor Arrays for Hot Carrier Lifetime Enhancement,"
	International Reliability Physics Symposium Proceedings 2003, pp. 608-609 (2 pages in length).
AH	D. Brisbin et al., "Hot Carrier Reliability of N-LDMOS Transistor Arrays for Power BiCMOS Applications," International
	Reliability Physics Symposium Proceedings 2002, pp. 105-110 (6 pages in length).
AI	U.S. Patent Application No. 10/266,543, filed October 8, 2002, entitled: "Method and device for improving hot carrier
	reliability of an LDMOS transistor using drain ring over-drive bias," by Douglas Brisbin et al., 16 pages in length.

Examiner	Date Considered				
Examiner: Initial if citation considered, whether or not citation is in c	onformance with MPEP Section 609: Draw line through citation if				
not in conformance and not considered. Include conv of this form with next communication to applicant					